JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY KAKINADA
KAKINADA – 533 003, Andhra Pradesh, India
DEPARTMENT OF ELECTRICAL AND ELECTRONICS ENGINEERING

II Year I Semester		L	T	P	C
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ELECTRONIC DEVICES AND CIRCUITS LAB					

Preamble:
The aim of the lab imparts the knowledge to understand the concepts, working and characteristics of Different Diodes, BJT and FET Transistors, amplifiers and compensation techniques of transistors

Course Objectives: The student is able

- To study the characteristics of electronic components and measuring instruments.
- To understand the characteristics of PN, Zener diode, design rectifiers with and without filters
- To understand the characteristics of BJT, FET, MOSFET, SCR, UJT
- To understand the biasing of transistors
- To understand the frequency response of amplifiers, measure frequency, phase of signals.

Electronic Workshop Practice:

1. Identification, Specifications, Color Codes for resistor, R, L, C Components, Potentiometers, Coils, Gang condensers, Relays, Bread Boards.
2. Identification, Specifications and Testing of active devices, Diodes, BJTs, JFETs, LEDs, LCDs, SCR, UJT.
3. Soldering Practice- Simple circuits using active and passive components.
4. Study and operation of Ammeters, Voltmeters, Transformers, Analog and Digital
5. Multimeter, Function Generator, Regulated Power Supply and CRO.

List of Experiments
(Any 10 of the following experiments are to be conducted)

1. P.N Junction Diode Characteristics
   Part A: Germanium Diode (Forward bias& Reverse bias)
   Part B: Silicon Diode (Forward Bias only)
2. Zener Diode Characteristics
   Part A: V-I Characteristic
   Part B: Zener Diode as Voltage Regulator
3. Rectifiers (without and with c-filter)
   Part A: Half-wave Rectifier
   Part B: Full-wave Rectifier
4. BJT Characteristics (CE Configuration)
   Part A: Input Characteristics
   Part B: output Characteristics
5. FET Characteristics
   Part A: Drain Characteristics
   Part B: Transfer Characteristics
6. SCR Characteristics

7. UJT Characteristics
8. MOSFET Characteristics
9. Transistor Biasing
10. Measurement of electrical quantities using CRO
11. BJT-CE Amplifier
12. Emitter Follower –CC Amplifier
13. FET-CS Amplifier

Note: The students are required to perform the experiment to obtain the V-I characteristics and to determine the relevant parameters from the obtained graphs.

Equipment required:

1. Regulated Power supplies
2. Analog/Digital Storage Oscilloscopes
3. Analog/Digital Function Generators
4. Digital Multi-meters
5. Decade Résistance Boxes/Rheostats
6. Decade Capacitance Boxes
7. Ammeters (Analog or Digital)
8. Voltmeters (Analog or Digital)
9. Active & Passive Electronic Components

Course Outcomes: At the end of the course, student will be able to

- Analyze the characteristics of diodes, transistors and other devices
- Design and implement the rectifier circuits, SCR and UJT in the hardware circuits.
- Design the biasing and amplifiers of BJT and FET amplifiers
- Measure electrical quantities using CRO in the experimentation.